# NSN 5962-01-393-6093

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# Maximum Power Dissipation Rating:

1.0 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

# Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **End Application:**

Pacer dawn

#### **Features Provided:**

Burn in and electrostatic sensitive and monolithic and ultraviolet erasable and programmed

#### **Inclosure Material:**

Ceramic

Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

#### **Input Circuit Pattern:**

13 input

#### **Criticality Code Justification:**

Feat

### Case Outline Source And Designator:

D-9 mil-m-38510

# **Terminal Surface Treatment:**

Solder

### **Product Name:**

Microcircuit, programmed-uv eprom, 64k (8k x8)

#### Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

#### Memory Device Type:

Eprom

#### **Special Features:**

Electrostatic discharge sensitive; altered item, make from p/n 5962-8751501la

#### Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### Terminal Type And Quantity:

24 printed circuit

#### Shelf Life:

N/a

### Unit Of Measure:

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# Demilitarization:

No

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